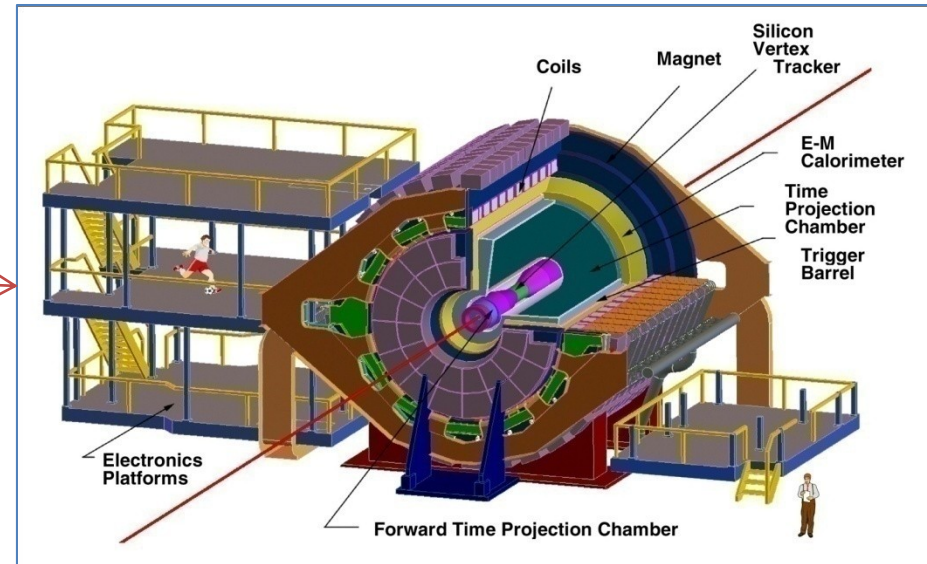


STAR Heavy Flavor Tracker Upgrade --PXL Detector

*Xiangming Sun
Lawrence Berkeley National Lab*

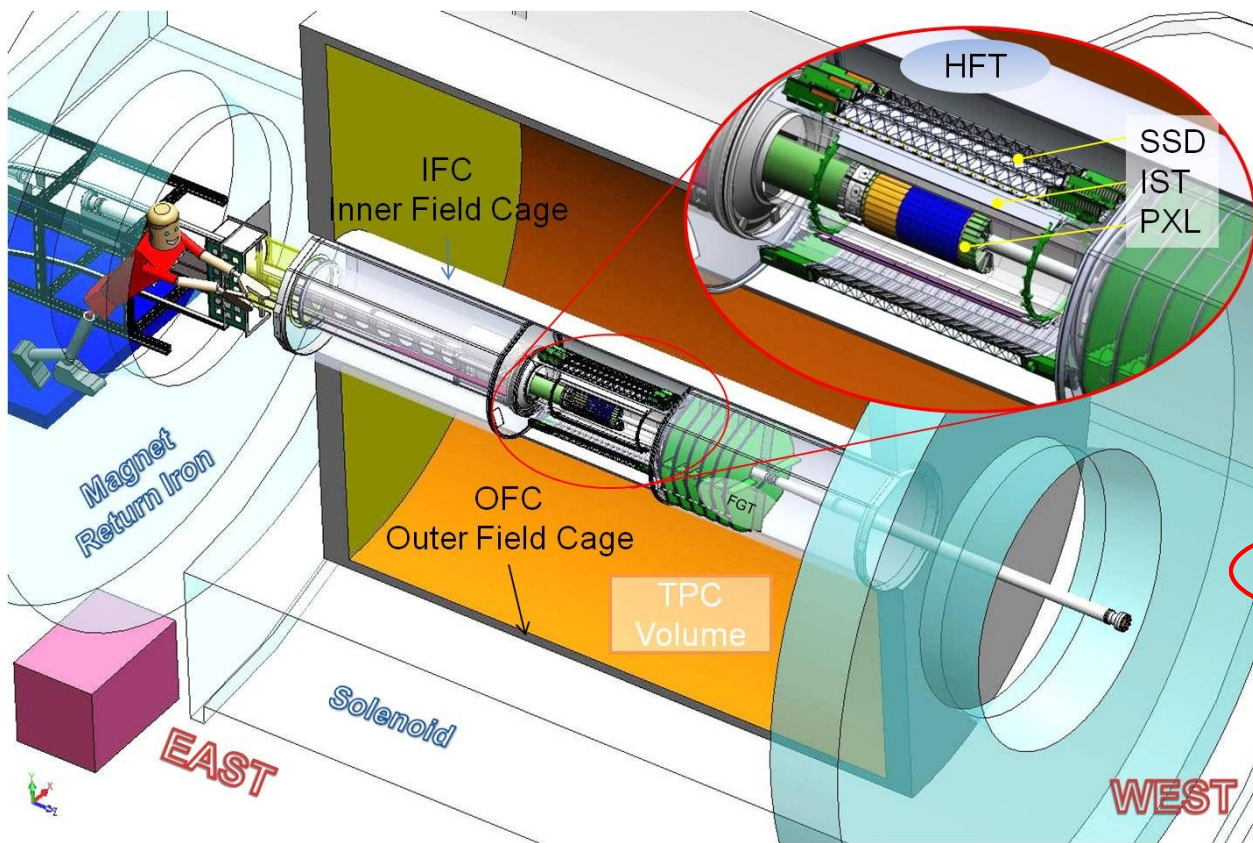
L. Greiner,
H. Matis
J. Schambach
T. Stezelberger
M. Szelezniak
C. Vu
H. Wieman

- Heavy Flavor Tracker upgrade in STAR at RHIC
- PXL detector architecture
- Cooling and vibration testing
- Monolithic Active Pixel Sensor for PXL
- PXL Readout Electronics
- Summary



RHIC (Relativistic heavy ion collider)
 Brookhaven National Lab
<http://www.bnl.gov/rhic/>

STAR (the solenoidal tracker at RHIC) is one of the Detectors at RHIC. It specializes in tracking the thousands of particles produced by each ion collision.

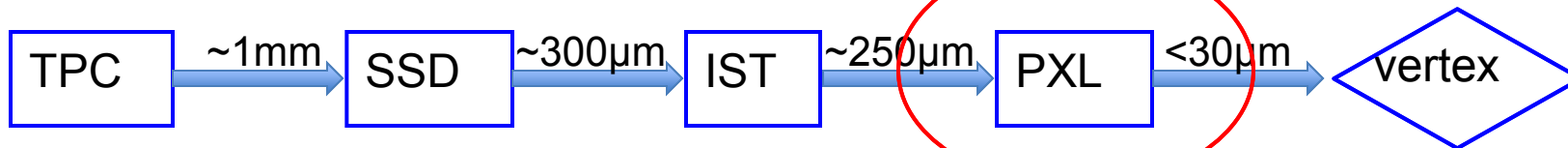


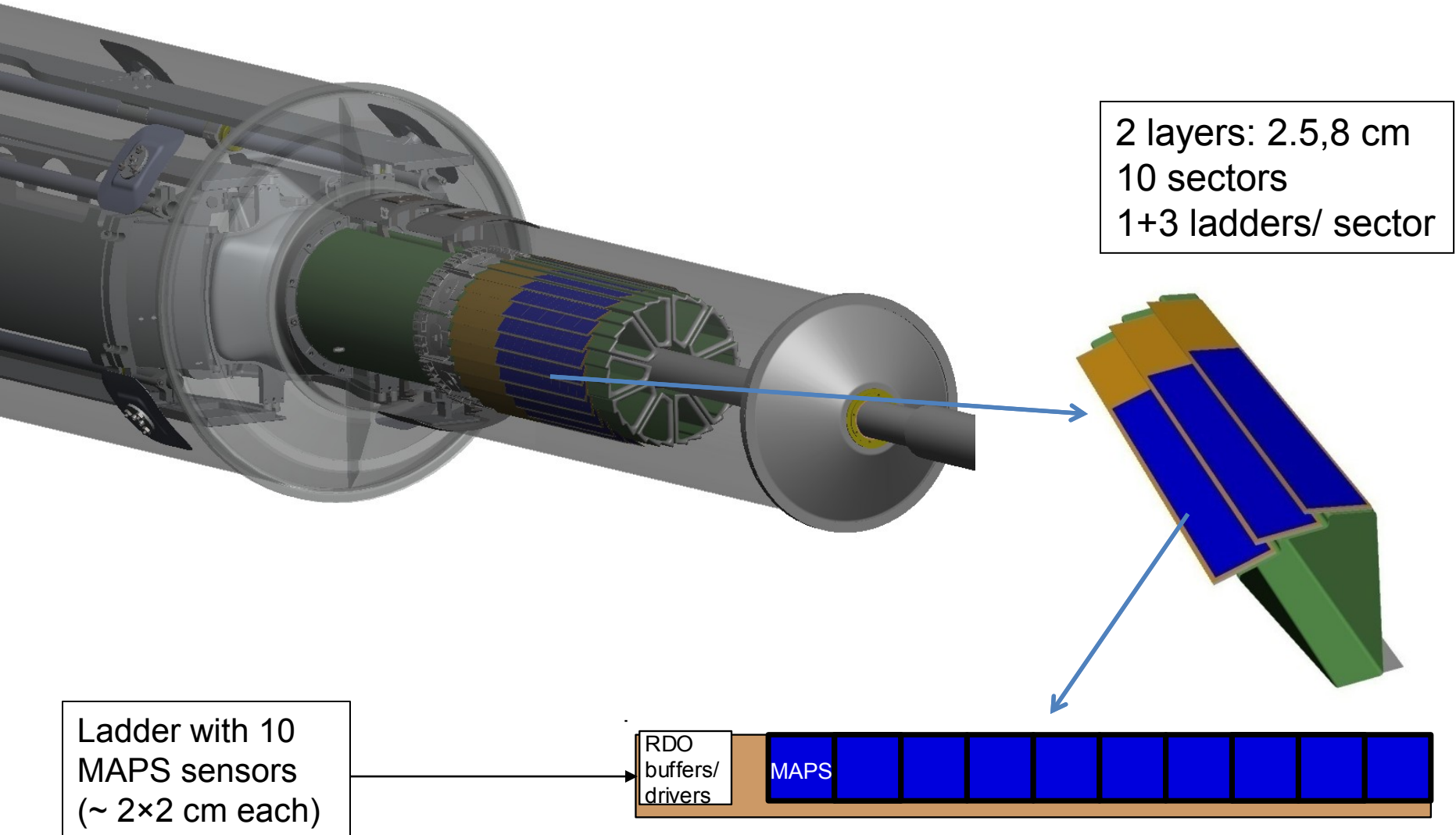
TPC – Time Projection Chamber
(main tracking detector in STAR)

HFT – Heavy Flavor Tracker

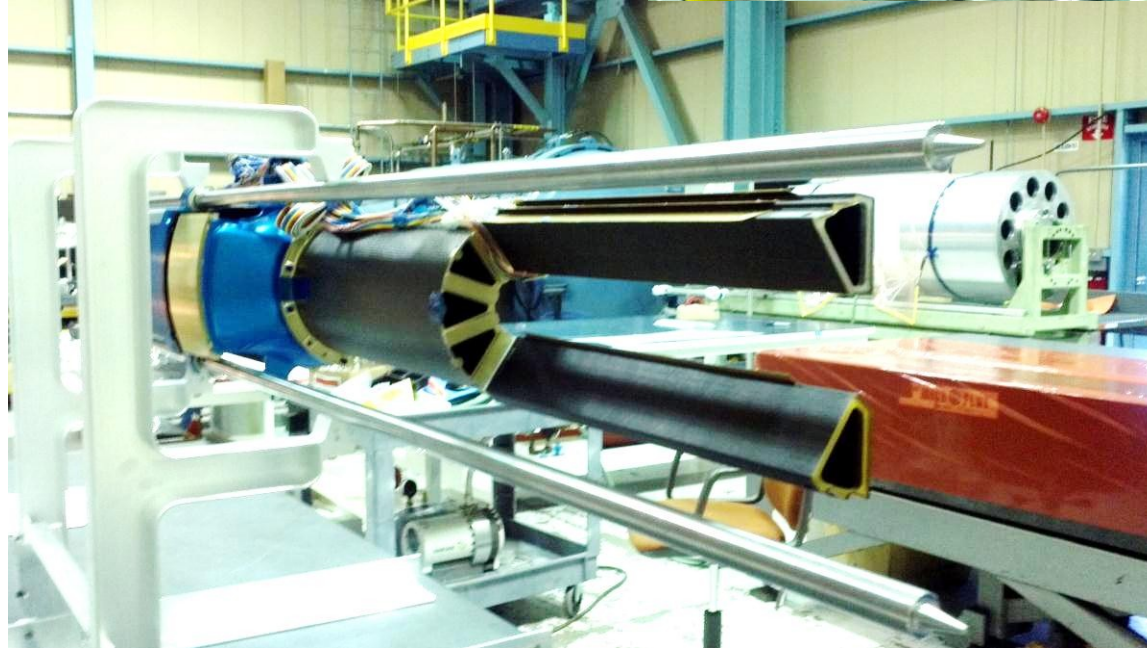
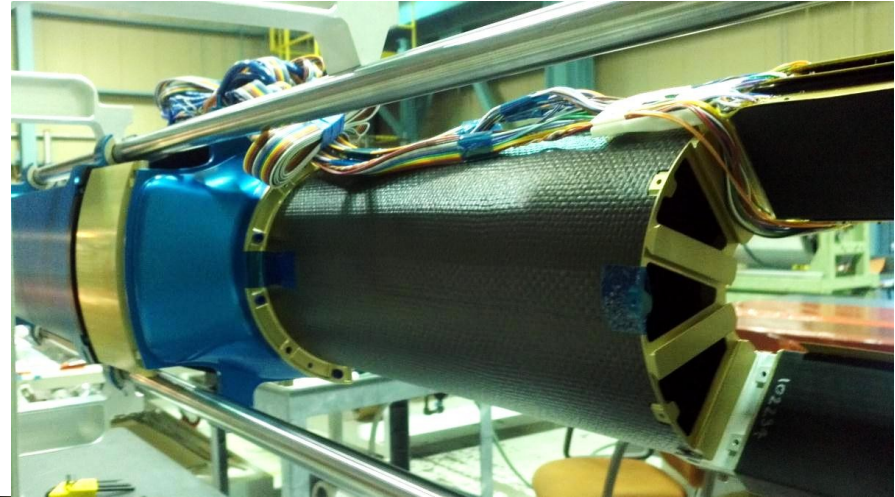
- SSD – Silicon Strip Detector
 - $r = 22$ cm
- IST – Inner Silicon Tracker
 - $r = 14$ cm
- PXL – Pixel Detector
 - $r = 2.5, 8$ cm

We track inward from the TPC with graded resolution:





PXL Mechanical Construction

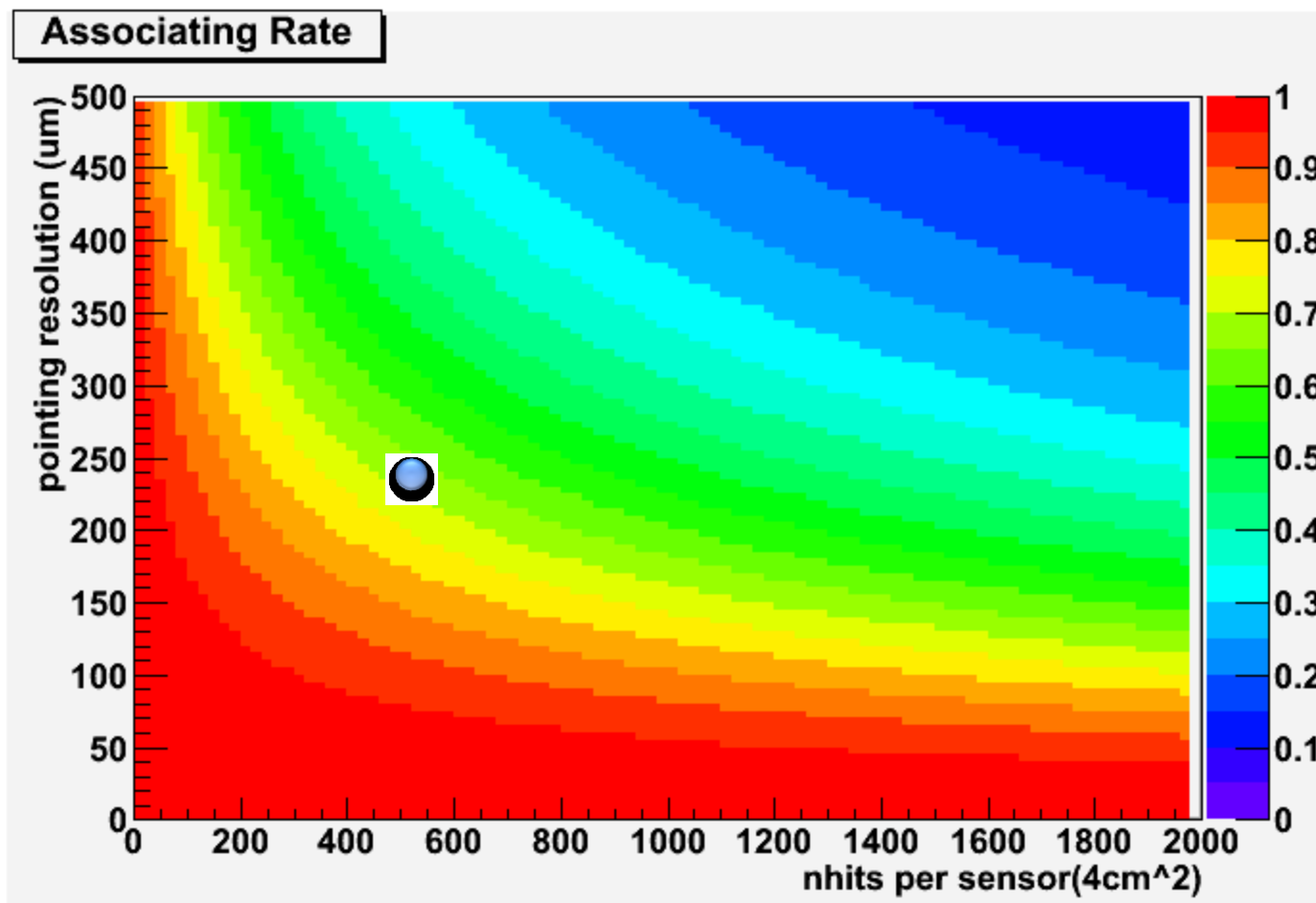


http://rnc.lbl.gov/hft/hardware/docs/ultimate/HFT_Mechanics_20110428.pptx

Some PXL Parameters

Pointing resolution from outer detector	250 μ m(TPC,SSD, IST) (12 \oplus 19 GeV/p.c) μ m
Layers	Layer 1 at 2.5 cm radius Layer 2 at 8 cm radius
Pixel size	\sim 20 μ m X 20 μ m
Position stability	6 μ m rms (20 μ m envelope)
Radiation thickness per layer	X/X0 = 0.37%
Integration time (affects pileup)	186 μ s
Number of pixels	400 M
Radiation tolerance	75 kRad/year $5 \cdot 10^{11}$ - $1 \cdot 10^{12}$ n_{eq}
Rapid detector replacement	< 8 hours

critical and difficult



Association rate: associating hits to tracks from outer detector

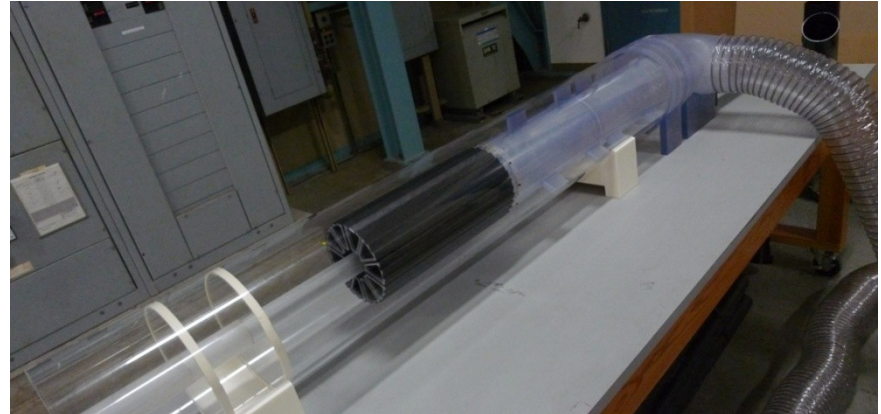
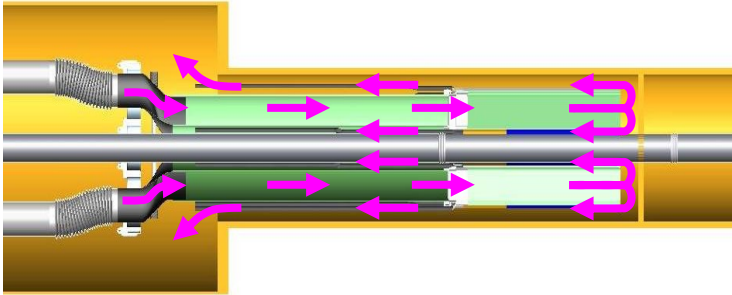
Nhits per sensor=500 for 200us integration time

Pointing resolution=250um

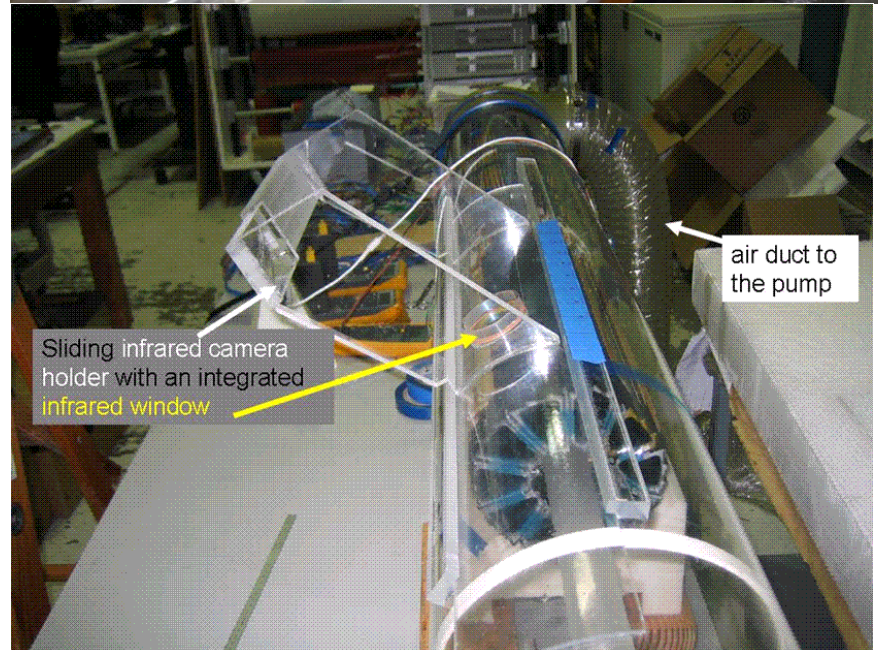
Association rate=67%

Cooling and vibration testing

- Sensor: 170 mW/cm^2 → 270 W for PXL sensors
- 2 W/drivers/cable → 80 W for PXL drivers



Silicon heater on 1 sector
PCB heaters on 9 sectors

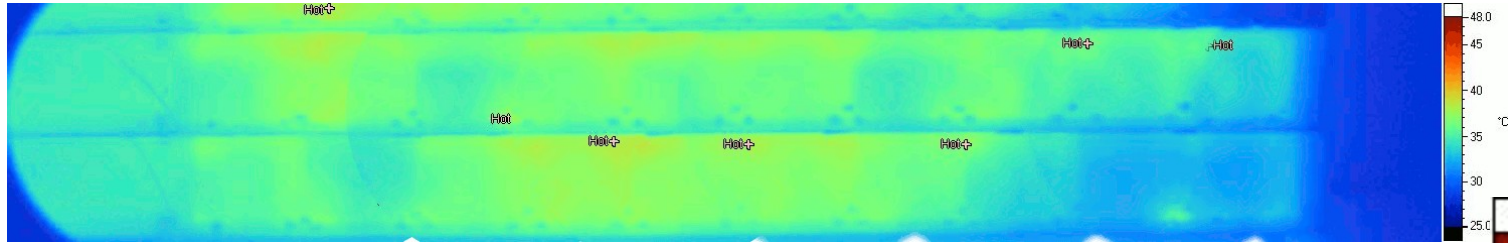


Cooling Tests at ~360 W – IR Images

From infra-red camera

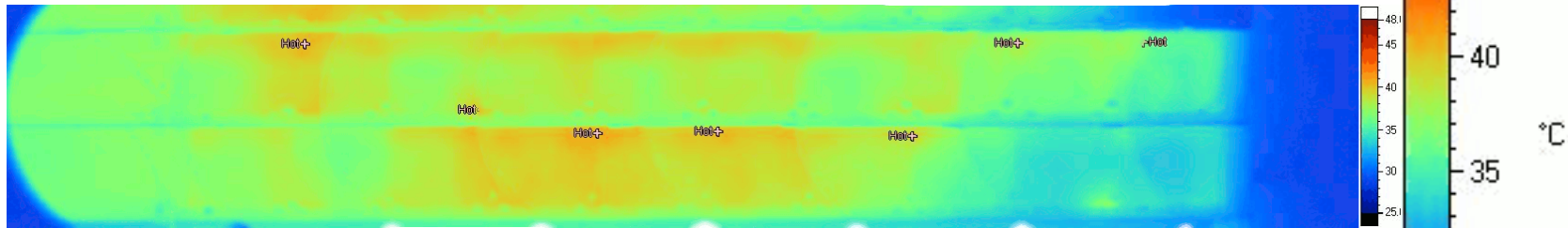
Air 13.8 m/s

Hot spots ~37 °C



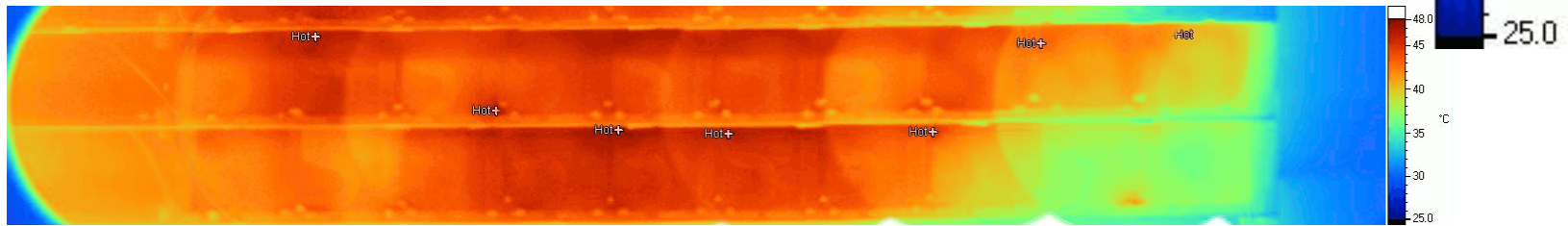
Air 10.1 m/s

Hot spots ~41 °C



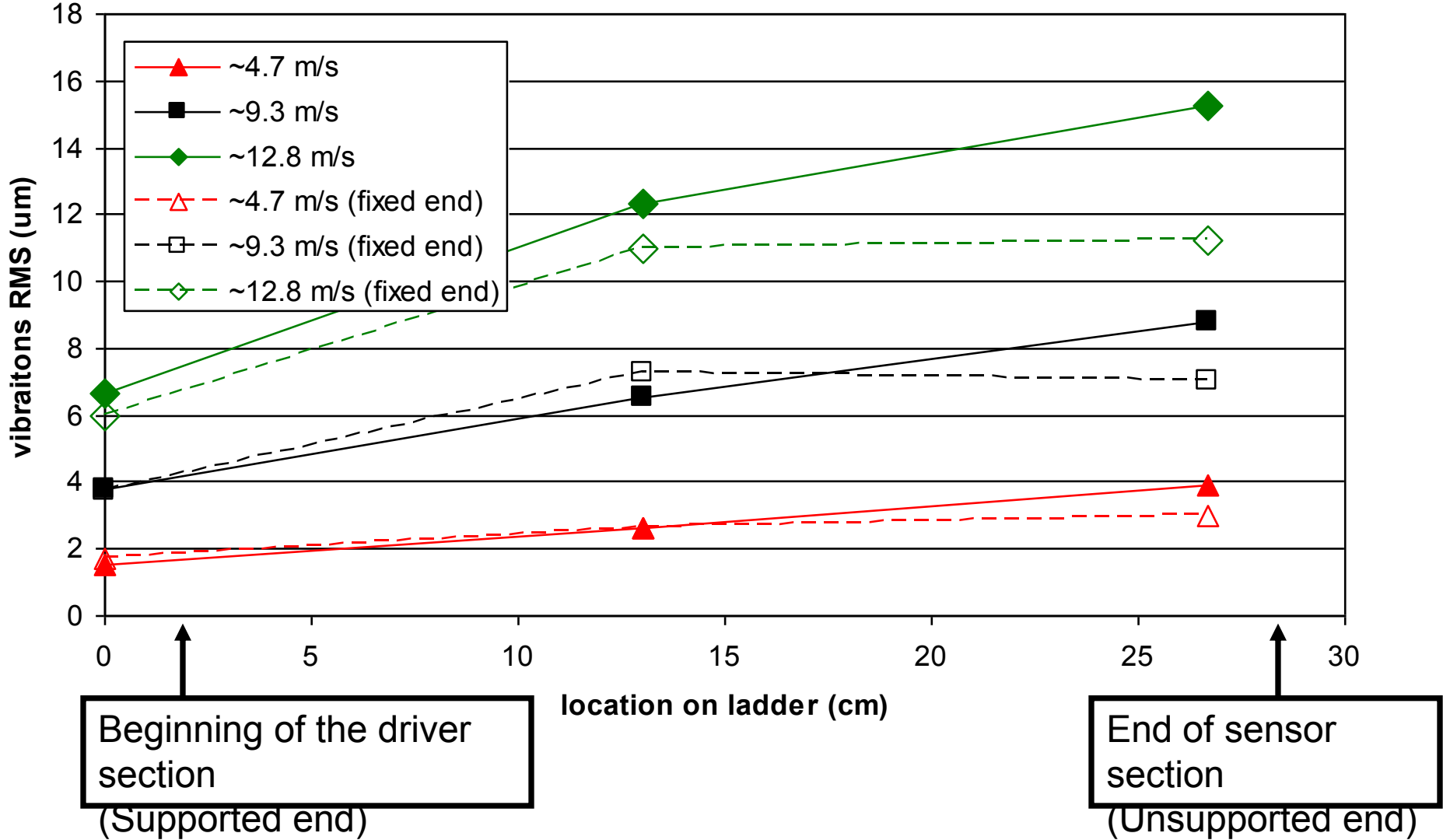
Air 4.7 m/s

Hot spots ~48 °C

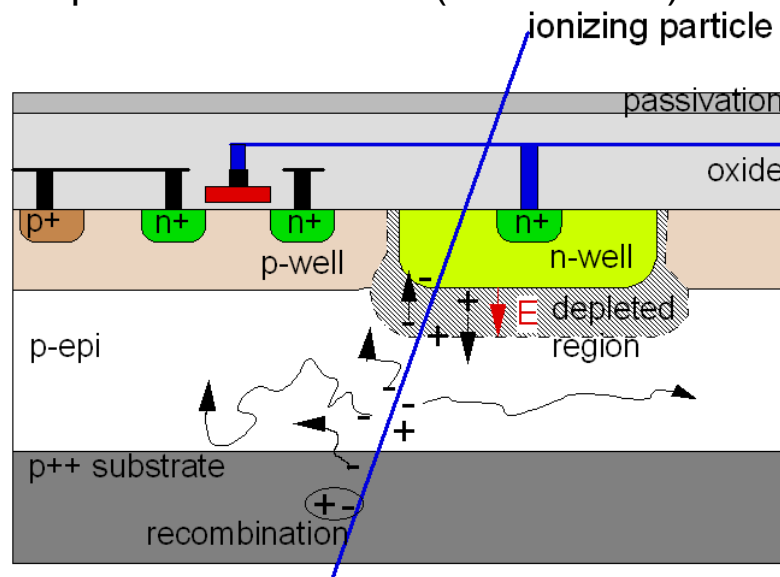
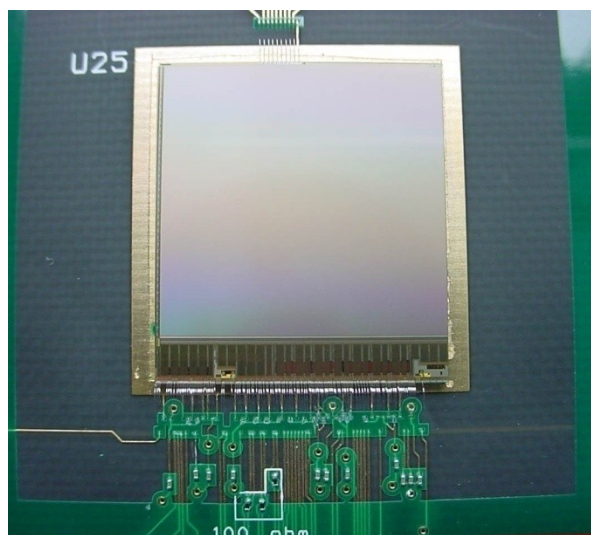


Air temperature ~27 °C

Using capacitance sensor to measure vibration

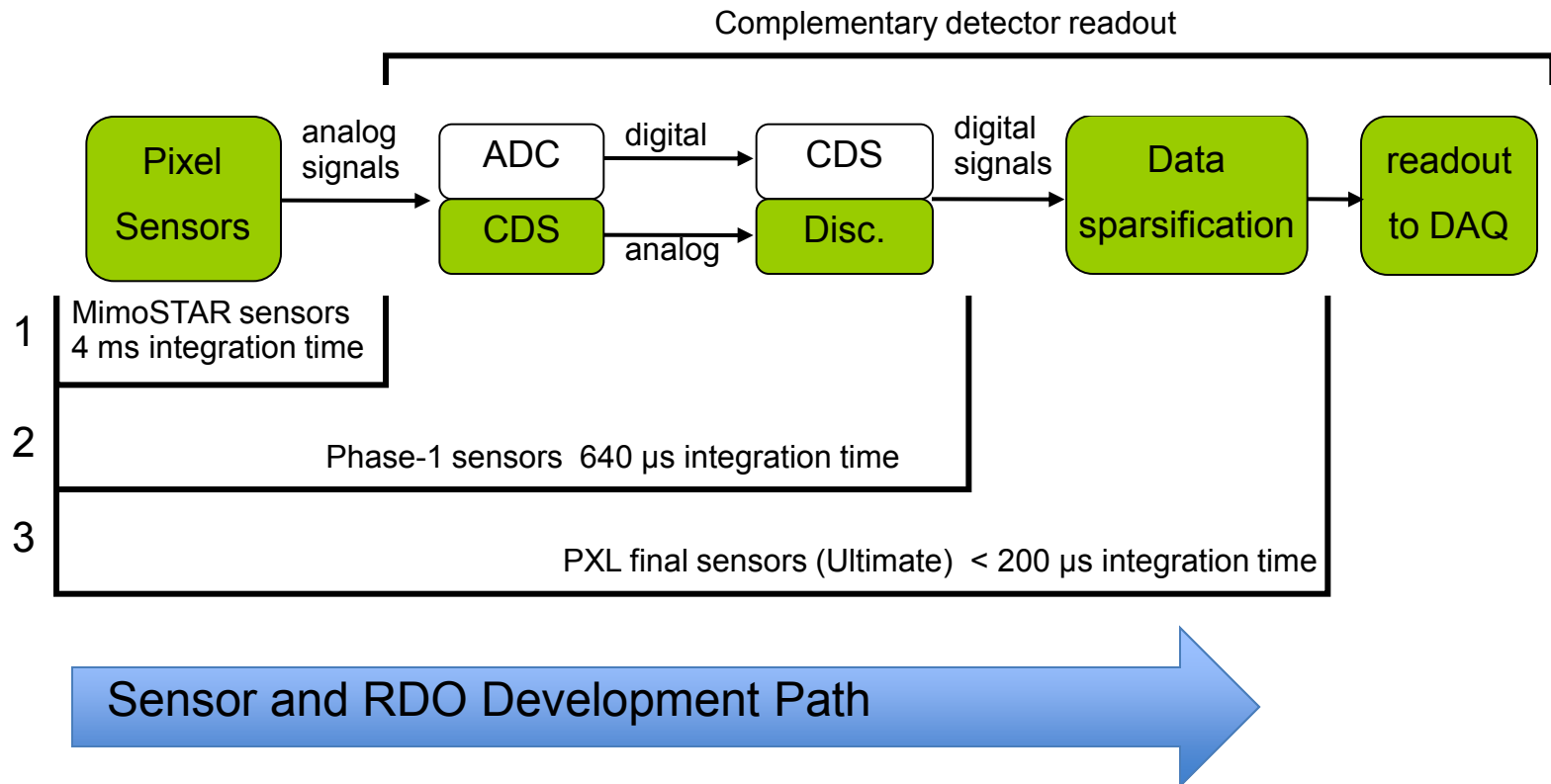


MAPS pixel cross-section (not to scale)

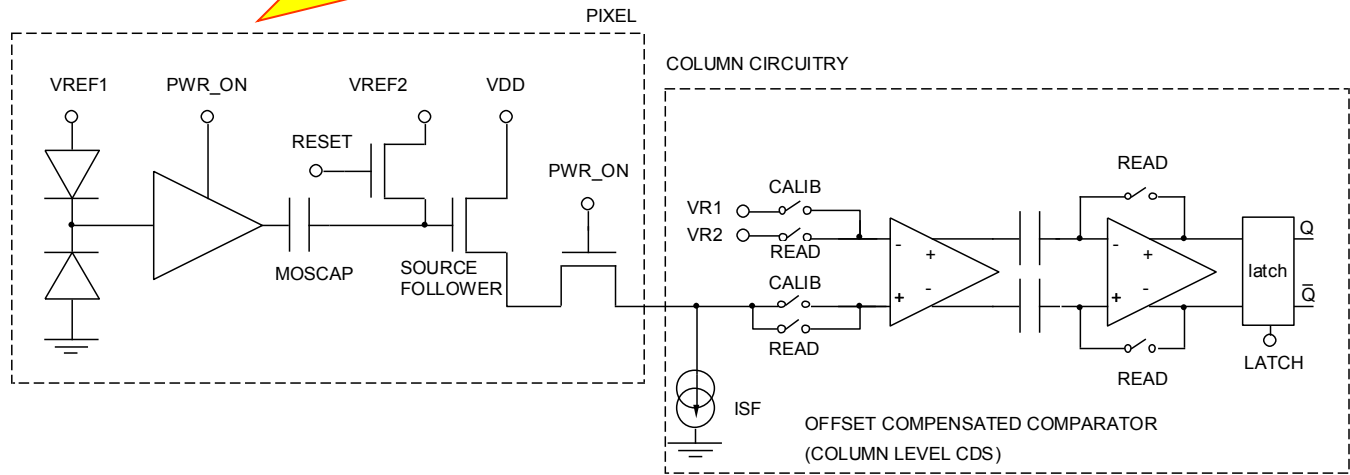
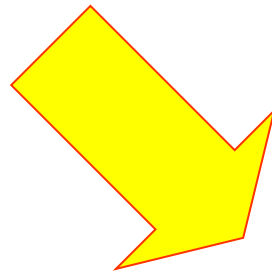
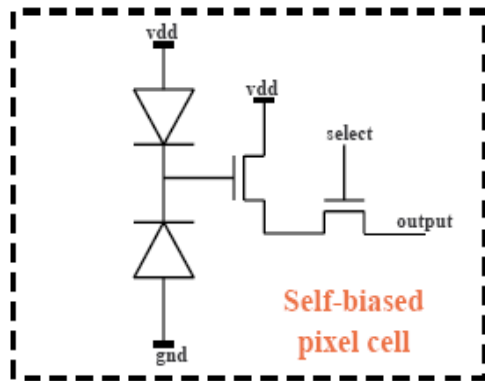


- IPHC-DRS (former IRES/LEPSI) proposed using MAPS for high energy physics in 1999
- Standard commercial CMOS technology
- Sensor and signal processing are integrated in the same silicon wafer
- Proven thinning to 50 micron
- Signal is created in the low-doped epitaxial layer (typically $\sim 10\text{-}15\ \mu\text{m}$) \rightarrow MIP signal is limited to <1000 electrons
- Charge collection is mainly through diffusion (~ 100 ns), reflective boundaries at p-epi and substrate \rightarrow cluster size is about ~ 10 pixels ($20\text{-}30\ \mu\text{m}$ pixel pitch)
- Room temperature operation

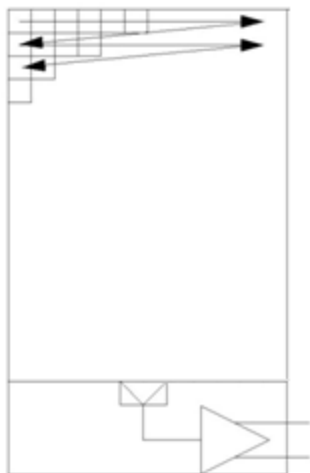
3 generation program with highly coupled sensor and readout development



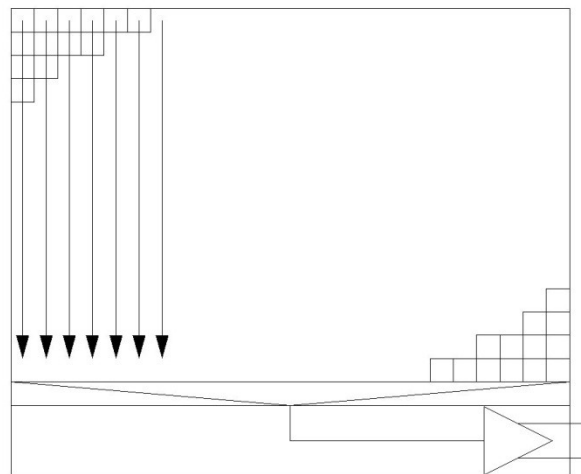
Analog readout – simpler architecture but slower readout



Digital readout – offers increased speed but requires on-chip discriminators or ADCs and increased S/N for on-chip signal processing



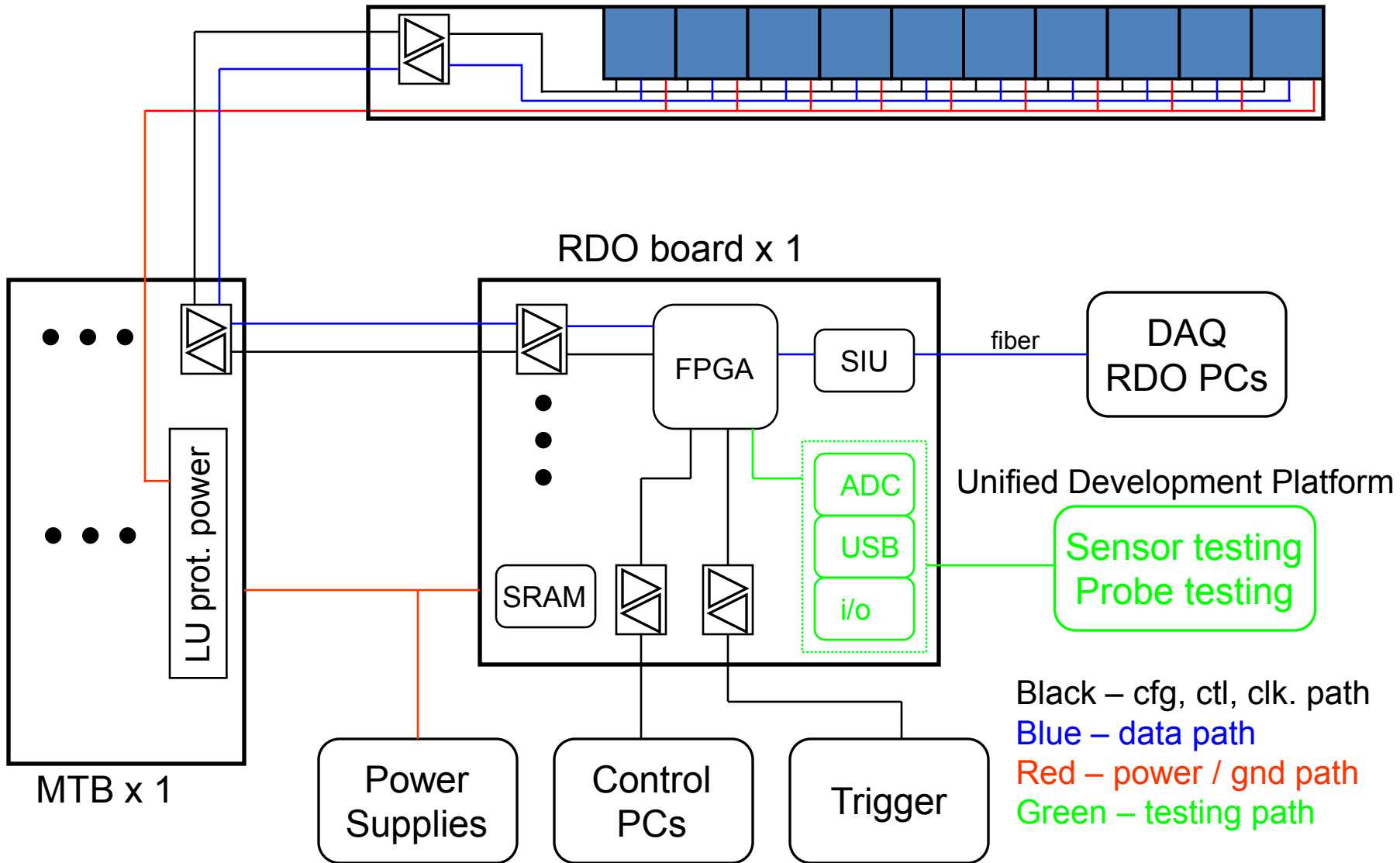
- Typical sensor readout
 - “rolling shutter” mode.
 - Integration time = array readout time

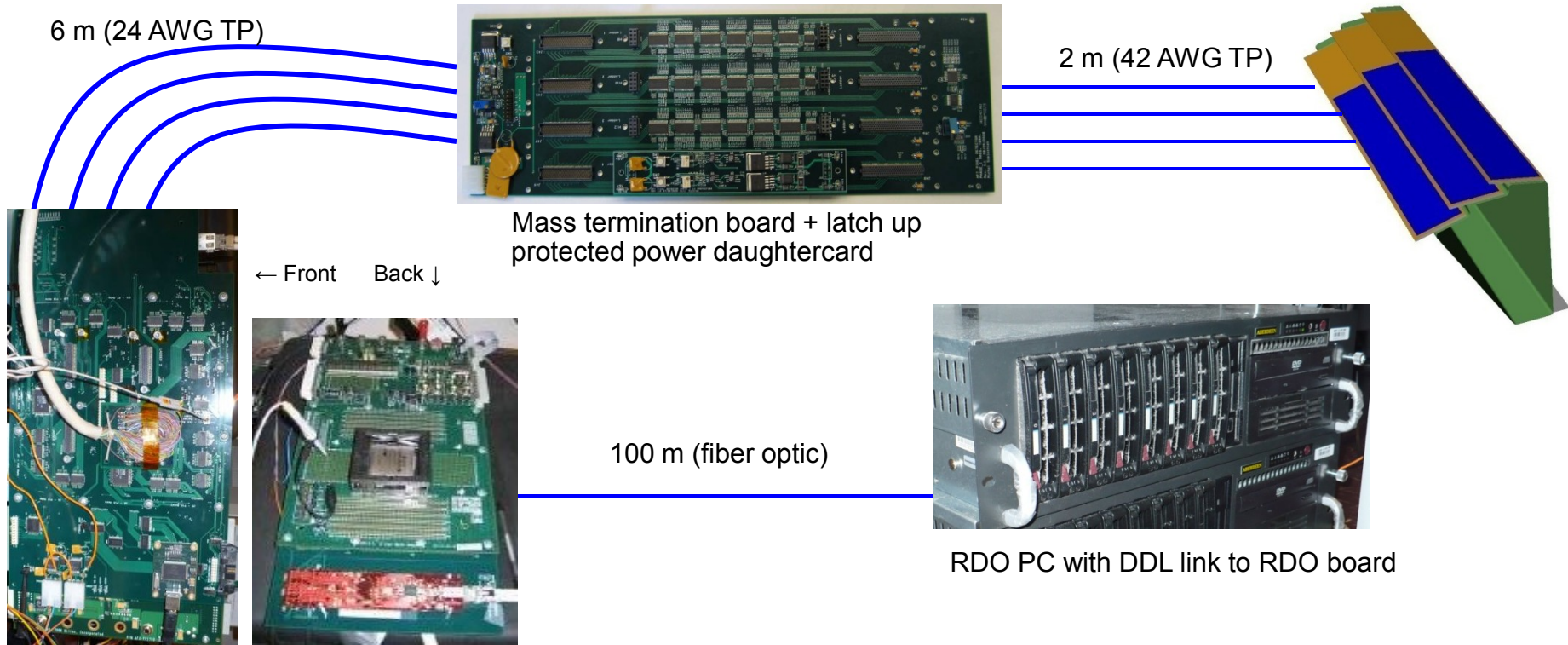


- Column parallel readout architecture
 - All columns readout in parallel and then multiplexed to one output
 - Integration time = column readout time
 - Integration time = **200 us**

PXL Readout Schematics

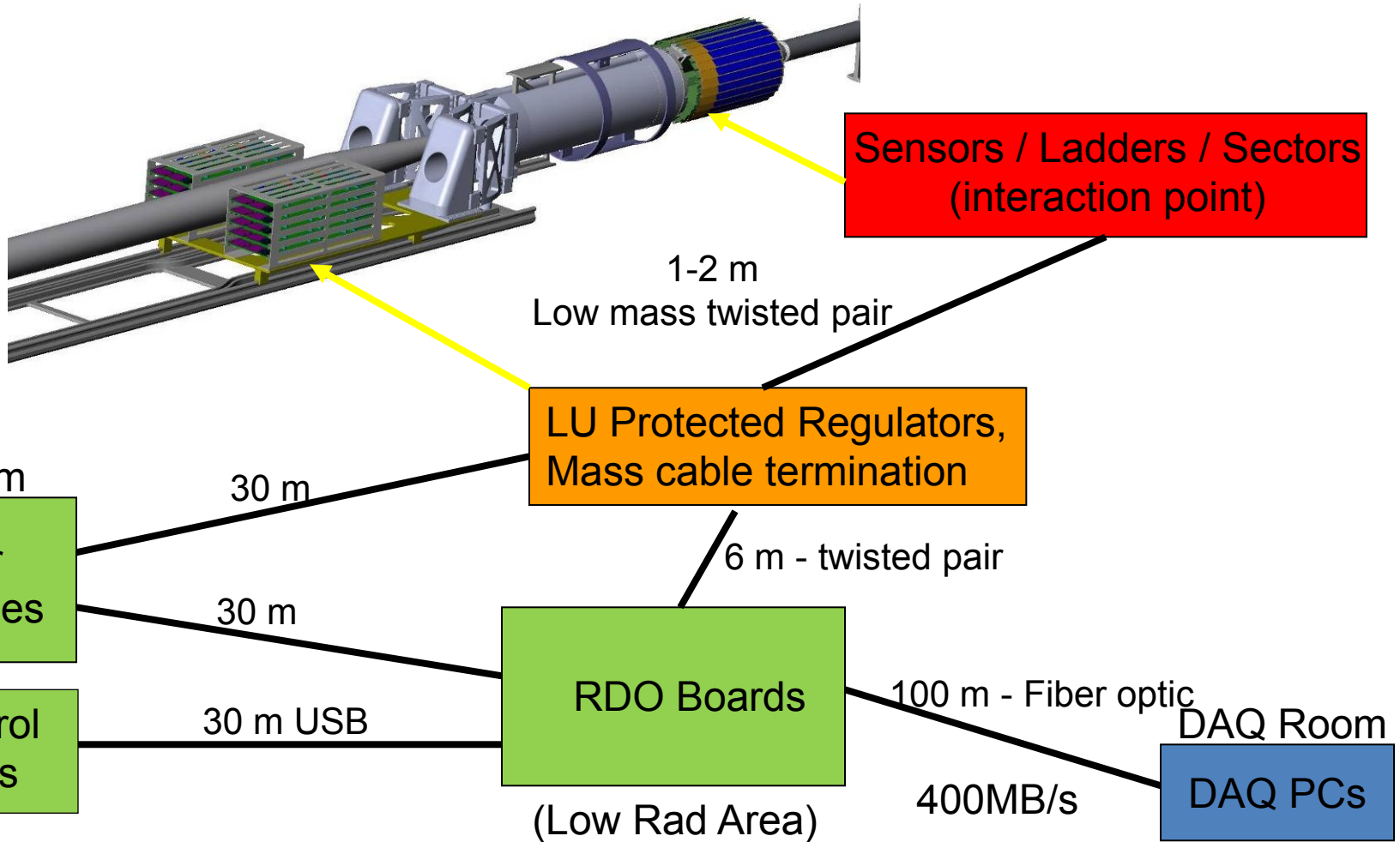
Ladder x 4





- 4 ladders per sector
- 1 Mass Termination Board (MTB) per sector
- 1 sector per RDO board
- 10 RDO boards in the PIXEL system

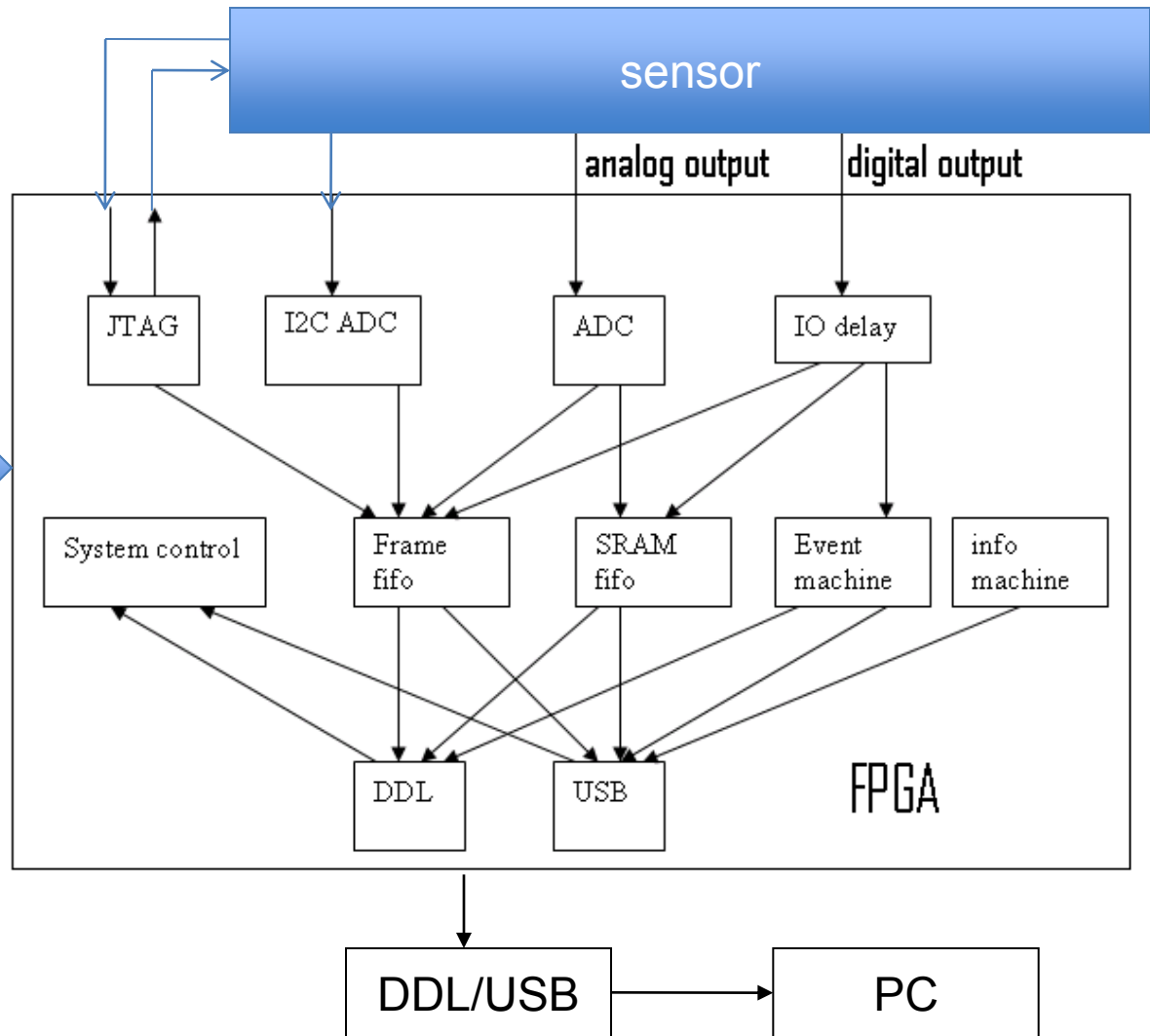
RDO System Design – Physical Layout



Firmware Structure



Xilinx Virtex-5 Dev Board



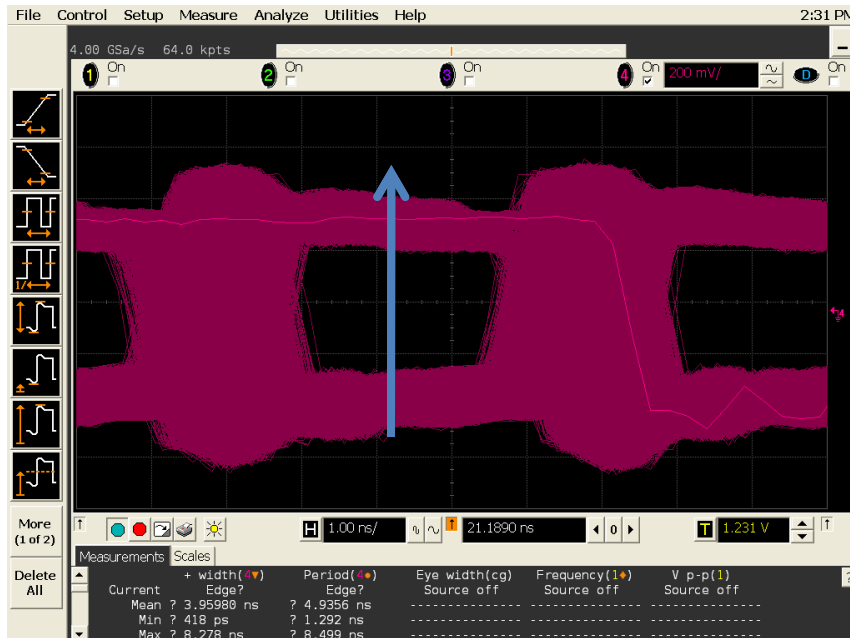


IO Delay for Digital Data Alignment

800 channels, 160 MHz digital signals pass 8 meters before arriving FPGA.

digital need to be aligned in FPGA end.

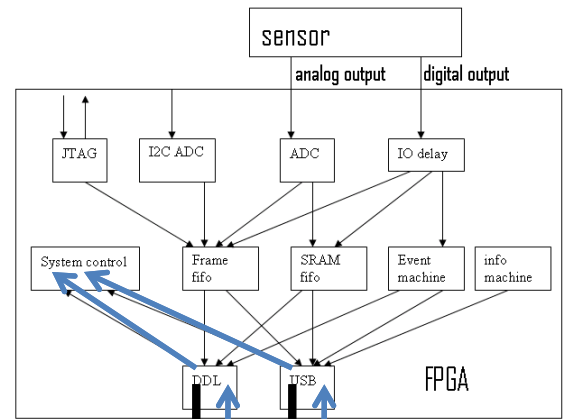
Solution: FPGA iodelay function



Status

- Data Path Architecture Validated
- Measured BER (bit error rate) of $< 10^{-14}$

Command generator:
command.exe



0x0402fffd
 0x1d82ff3f
 0x1502ffcf
 0x2642ffff
 0x2642fdff
 0x2202feff
 0x0c03fff0
 0x1547ffff
 0x1547ffff
 0x1547ffff
 0x1547ffdf
 0x0cc7ffff
 0x0cc7ffff



download_data_block_to_FEE

USB upload

rorc_receive

USB download



Our current status:

Layer thickness	X/X0=0.37%
Air speed	~10 m/s
Senor temp arise	14 °C
Vibration	<8 um rms
The integration time	186 us
Readout Electronics	prototyped and works as required

The PXL is expected to be fully installed in 2013 for RHIC Run14

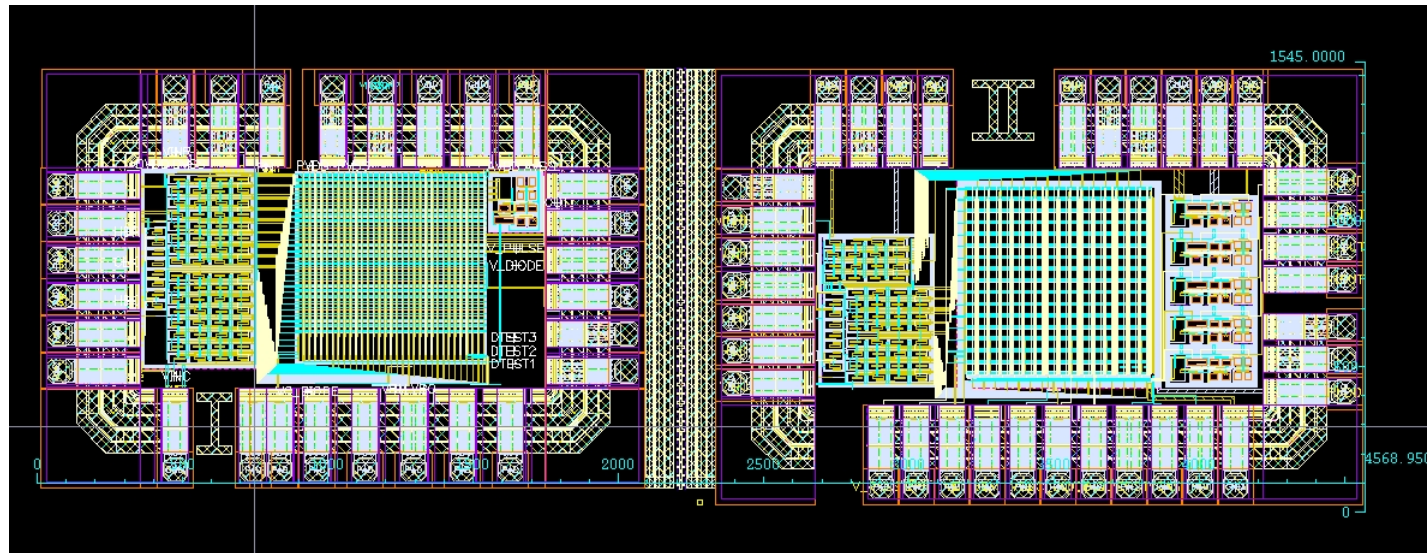
CCNU plans to in study Pixel sensor. (Nu Xu proposed)

Pixel sensor in high energy physics is a good opportunity for CCNU to start

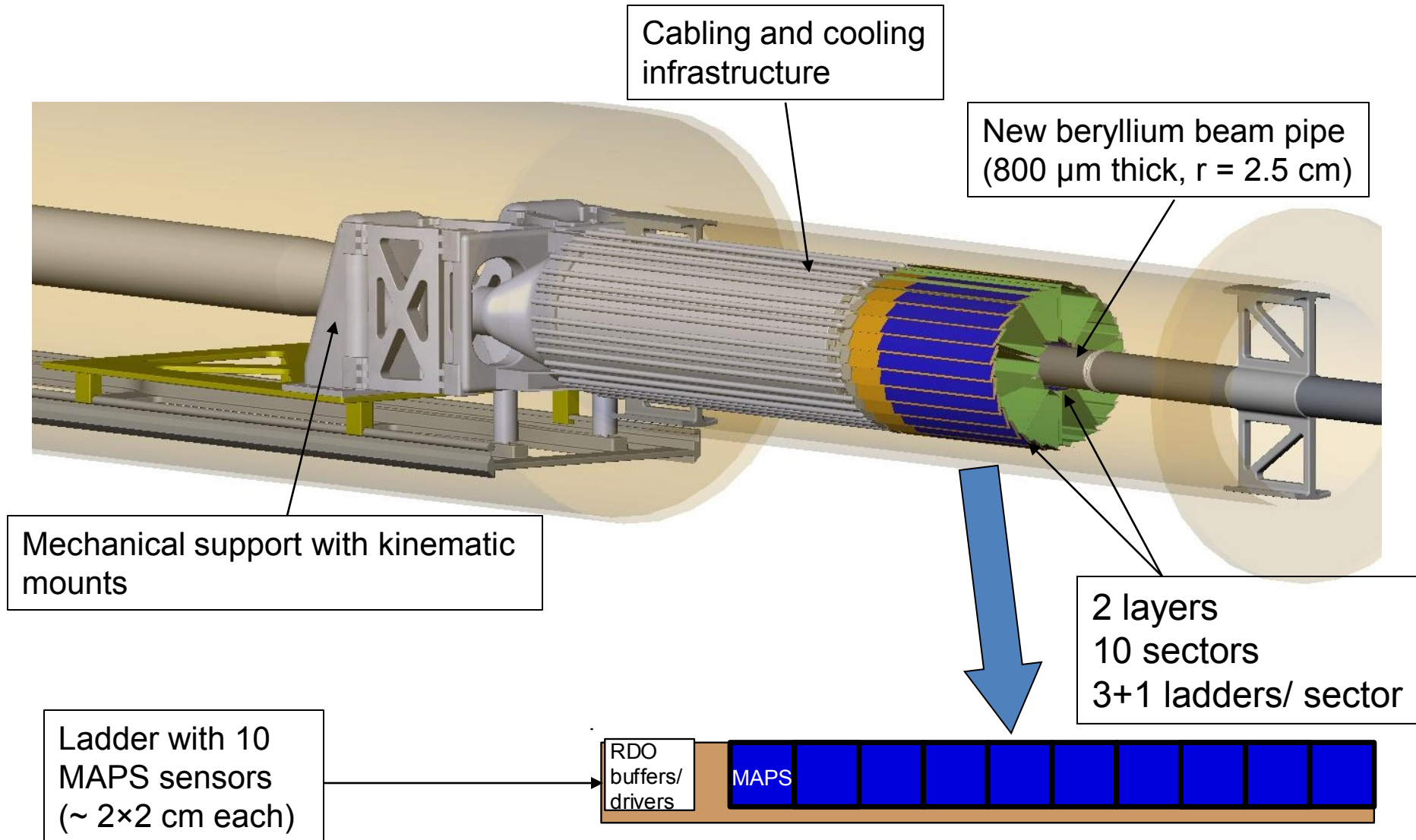
Try to be familiar with IC design environment(2 student)

Try to be familiar with XFAB technology

0.35 MPW in May 20 in XFAB.



PXL Detector



Direct measurement has not been done so far.

Based on estimates ([http://rnc.lbl.gov/~wieman/radiation dose straus oct 2007 HW.ppt](http://rnc.lbl.gov/~wieman/radiation_dose_straus_oct_2007_HW.ppt)) and TLD projection.

- For the radius of 2.5 cm:
 - Ionizing radiation:
 - Total dose: 155 kRad
 - TLD projection: 300 kRad
 - Non-ionizing radiation
 - average pion count for 1 Yr: 3×10^{12} cm⁻²
 - TLD projection (pion assumption): 12×10^{12} cm⁻²

MIMOSA-22 Testing in 10 KeV X-Rays in Lab

▷ ex. of S6 (M22) variants at 20° C

* before irradiation $\gtrsim 9.5 e^- ENC$

* after 50 kRad $\gtrsim 11 e^- ENC$

* after 150 kRad $\gtrsim 13 e^- ENC$

* after 300 kRad $\gtrsim 15 e^- ENC$

MIMOSA-22ter

* after 300 kRad $\lesssim 15 e^- ENC$

Signal/noise ratio ≥ 20 after 300 kRad Ionizing radiation (300 e⁺e⁻ pairs)
Non-ionizing radiation is under investigation

- The Heavy Flavor Tracker (HFT) is an upgrade project for the STAR detector at RHIC, It will allow the topological reconstructions of the heavy flavor hadrons via their hadronic decays . The HFT consists of three coaxial detectors: SSD(Silicon Strip Detector), IST(Intermediate Si-Tracker) and PIXEL(a pixel detector). The PIXEL is the inner-most and highest precision detector in HFT. The sensor chip we use to build PIXEL is developed in Monolithic Active Pixel Sensor(MAPS) technology. Each sensor has 1024X1188 pixels with 18.4 micron pitch and 50 micron thickness. The integration time is 200 us. Correlated double sampling (CDS) and digitization are performed on the sensor chip. The readout electronics is designed to handle 400 sensors which are grouped in 10 sectors. In this talk, we discuss the relation between the physics goals and sensor characteristics, such as pixel size, sensor thickness, integration time, radiation tolerance and power consumption. We introduce the on-chip electronics design to perform CDS and digitization. We also show the readout electronics designed to handle R&D tests and physics data acquisition. The PIXEL is expected to be fully installed in 2014 for RHIC Run14

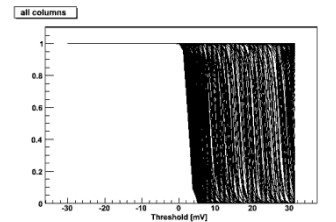
Status

- Automated and scripted system for sensor testing is in place.
- Vacuum chuck for handling up to twenty 50 μm thick sensors is being tested
- Ongoing sensor testing

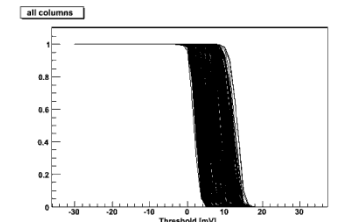


- Sensors designed with dedicated probe pads in the sensor pad ring.
- 13 full-thickness, diced sensors probe tested.
- Up to 3 probe tests on a sensor.
- We will begin testing thinned sensors within the next few days

Phase-1 discriminator transfer functions $f(\text{threshold voltage})$ observed on two of the probed sensors :



Initial testing with $\sim 75 \mu\text{m}$ travel past touchdown



30 μm additional lowering of probe pins

Cooling tests at ~360 W

- Initially: 100 mW/cm² → 160 W for PXL sensors
- Updated: x1.7 → 270 W for PXL sensor
- 2 W/drivers/cable → 80 W for PXL drivers

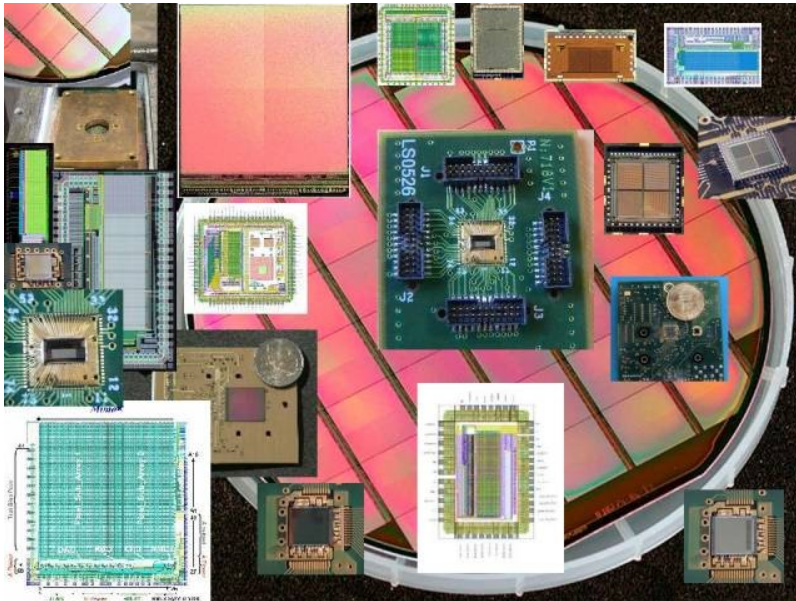
Ladder section		Measured resistance (Ω)	Current (A)	Voltage (V)	Power (I·V) (W)
sensors	Sector 1 (Pt heaters)	6.6	2.06	6.97 + 7.96	30.7
	Sectors 2-10	4.6 3.7	10.6	23.1	244.8
drivers	Sectors 1-5	1.4	5.3	8.23	43.6
	Sectors 6-10	1.4	5.3	8.03	42.5
Total Power					~361

STAR MAPS @ Institut Pluridisciplinaire Hubert Curien

- IPHC-DRS (former IRES/LEPSI) proposed using MAPS for high energy physics in 1999
- CMOS & ILC group today
 - 6 physicists
 - 9 microcircuit designers
 - 6 test engineers
 - 7 PhD students

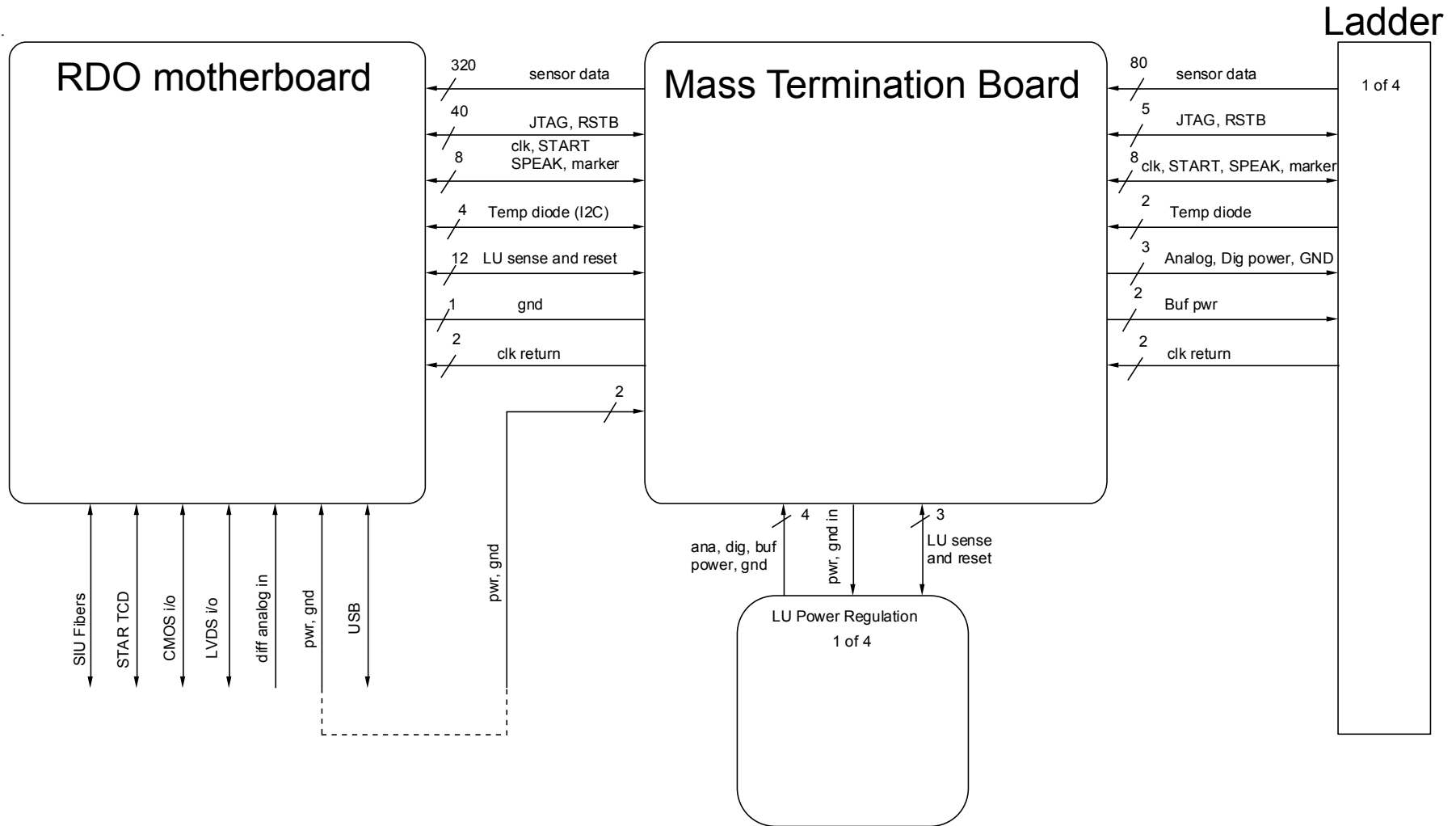


CNRS - IPHC, Strasbourg-Cronenbourg



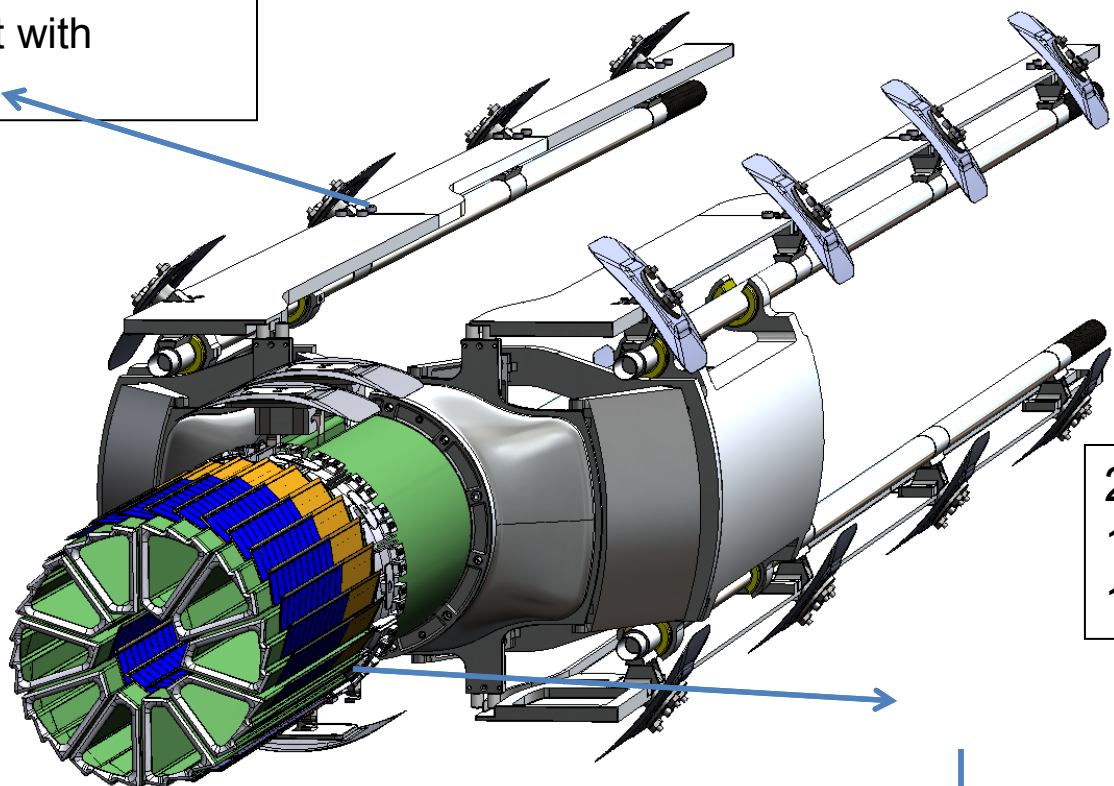
MIMOSA (Minimum Ionizing particle MOS Active sensor)

- More than 30 prototypes developed
 - several pixel sizes and architectures (simple 3-transistor cells, pixels with in-pixel amplifiers and CDS processing)
 - different readout strategies (sensors operated in current and voltage mode, analog and digital output)
 - Large variety of prototype sizes (from several hundreds of pixels up to 1M pixel prototype with full-reticule size)



PXL Detector

Mechanical support with kinematic mounts



2 layers: 2.5, 8 cm
10 sectors
1+3 ladders/ sector

Ladder with 10 MAPS sensors (~ 2x2 cm each)

